
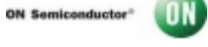
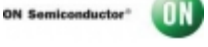
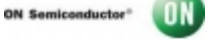



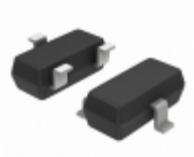
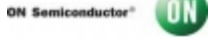
	<h2 style="color: red;">NVTR4503NT1G</h2>
	<p>Hersteller-Teilenummer: NVTR4503NT1G</p> <hr/> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 30V 1.5A SOT23</p> <hr/> <p>Datenblätter:  NVTR4503NT1G.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 57759 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NVTR4503NT1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 30V 1.5A SOT23
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	57759 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Verlustleistung (max)	420mW (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	1.5A (Ta)
Rds On (Max) @ Id, Vgs	110 mOhm @ 2.5A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	7nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	135pF @ 15V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)

NVTR4503NT1G ist neu im Original, Suche NVTR4503NT1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NVTR4503NT1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NVTR4503NT1G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NVTJD4401NT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 20V 0.63A SC-88</p>	 <p>NVTR0202PLT1G AMI Semiconductor / ON Semiconductor MOSFET P-CH 20V 0.4A SOT23</p>	 <p>NVTP2955G AMI Semiconductor / ON Semiconductor MOSFET 60V 12A 196</p>	 <p>NVTR01P02LT1G AMI Semiconductor / ON Semiconductor MOSFET P-CH 20V 1.3A SOT23</p>
 <p>NVTJD4105CT1G AMI Semiconductor / ON Semiconductor MOSFET 20V 0.63A SC-88</p>	 <p>NVTR4502PT O NVTR4502PT O</p>	 <p>NVTR4502PT1G AMI Semiconductor / ON Semiconductor MOSFET P-CH 30V 1.95A SOT23</p>	 <p>NVTS4409NT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V/8V 0.075A SC-70</p>

heiße Teile

Mehr

 1812AA561KAT1A	 A2V28S40BTP-75	 AP7335-20SNG-7	 AT89C51RC2-SLSUM	 AZ78L05MTR-G1
 B39162-B9839-P810	 B40CL40S02	 CAT25C256X-1.8	 CC1101RGPR	 DMN55D0UT-7
 ELM9818AB-S/N	 FAN53611UC123X	 FDMA7670	 FDN371N-NL	 FDS8410-NL
 FF150R12KE3_G	 GCM31A7U2E392JX01D	 GMK107BJ104KAHT	 GRM0335C1E2R7CD01D	 GRM1555C1E9R8DA01D
 HCPL-2611-000E	 HSMP-482B	 IR2308STRPBF	 IRFR9210TRLPBF	 IRKT132/16
 IRLM210ATF	 IRS2541STRPBF.	 IS61C256AH-20J	 K6T4016V3B-TB70	 LQW31HN15NJ03L
 MAZ33000HL	 MC34268DTRK	 MCC72-16ioB	 MIC2951-02BM	 N310CH12
 NFA18SL307V1A45L	 NVTR4502PT	 NVTR4502PT1G	 PAM2307BECADJR	 PCM69AU-J-T2
 RT8166BGQW	 RT9167A-30CS	 RTF020P02TL	 SA6.0A-E3/73	 SKY67013-396LF
 ST13003-142	 STM32F103RET6	 T2601N48TOF	 TE28F320B3BD70	 VI-211-CX

Contact us:Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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